

8.0SMDJ Series









Agency Recognitions

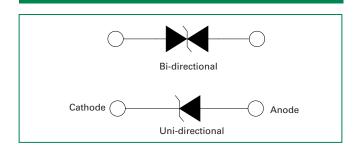
AGENCY	AGENCY FILE NUMBER
71	E230531

Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Peak Pulse Power Dissipation at T_L =25°C by 10/1000 μ s Waveform (Fig.2)(Note 1), (Note 2)	P _{PPM}	8000	W
Power Dissipation on Infinite Heat Sink at T_L =50°C	P _D	6.5	W
Peak Forward Surge Current, 8.3ms Single Half Sine Wave (Note 3)	I _{FSM}	300	А
Maximum Instantaneous Forward Voltage at 100A for Unidirectional Only	V _F	5.0	V
Operating Temperature Range	T _J	-65 to 150	°C
Storage Temperature Range	T _{STG}	-65 to 175	°C
Typical Thermal Resistance Junction to Lead	R _{eJL}	15	°C/W
Typical Thermal Resistance Junction to Ambient	R _{eJA}	75	°C/W

- 1. Non-repetitive current pulse , per Fig. 4 and derated above T_J (initial) =25°C per Fig. 3.
- 2. Mounted on copper pad area of 0.31x0.31" (8.0 x 8.0mm) to each terminal.
- 3. Measured on 8.3ms single half sine wave or equivalent square wave for unidirectional component only, duty cycle=4 per minute maximum

Functional Diagram



Description

The 8.0SMDJ series is designed specifically to protect sensitive electronic equipment from voltage transients induced by lightning and other transient voltage events.

Features

- For surface mounted applications to optimize board space
- Low profile package
- Typical failure mode is short from over-specified voltage or current
- Whisker test is conducted based on JEDEC JESD201A per its table 4a and 4c
- IEC-61000-4-2 ESD 30kV(Air), 30kV (Contact)
- ESD protection of data lines in accordance with IEC 61000-4-2
- EFT protection of data lines in accordance with IEC 61000-4-4
- Built-in strain relief
- Glass passivated chip junction
- 8kW peak pulse power capability at 10/1000µs waveform, repetition rate (duty cycles):0.01%
- Fast response time: typically less than 1.0ps from 0V to $V_{\rm BR}$ min
- Excellent clamping capability

- compact size with high power density in DO-214AB Package
- Low incremental surge resistance
- Typical I_R less than 5μA when V_{BR} min>22V
- High temperature reflow soldering guaranteed: 260°C/40sec
- V_{BR} @ T_J= V_{BR}@25°C $\times (1 + \alpha T \times (T_1 - 25))$ (a T:Temperature Coefficient, typical value is 0.1%)
- UL Recognized compound meeting flammability rating V-0
- Meet MSL level1, per J-STD-020, LF maximun peak of 260°C
- Matte tin lead–free plated
- Halogen free and RoHS compliant
- Pb-free E3 means 2nd level interconnect is Pb-free and the terminal finish material is tin(Sn) (IPC/ JEDEC J-STD-609A.01)

Applications

TVS components are ideal for the protection of I/O Interfaces, V_{cc} bus and other vulnerable circuits used in Telecom, Computer, Industrial and Consumer electronic applications.

TVS Diodes Surface Mount -8000W > 8.0SMDJ series

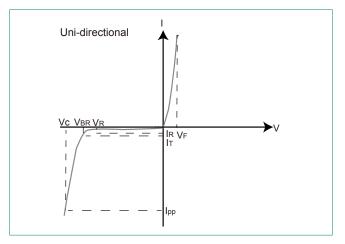
Electrical Characteristics (T_A=25°C unless otherwise noted)

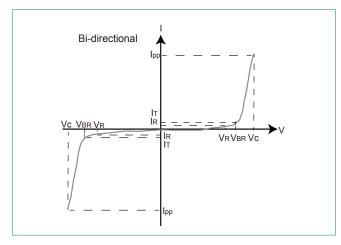
Part Number	Part Number	Mar	king	Reverse Stand off Voltage	Voltaç	down ge V _{BR} s) @ I _T	Test Current	Maximum Clamping Voltage V _c @	Maximum Peak Pulse Current I (10/1000µs)	Maximum Clamping Voltage V _c @ I	Maximum Peak Pulse Current I	Maximum Reverse Leakage I _R	Agency Approval
(Uni)	(Bi)	UNI	ВІ	V _R (Volts)	MIN	MAX	' _⊤ (mA)	(10/1000µs) (V)	(10/1000µs) (A)	(8/20µs) (V)	(8/20µs) (A)	@ V _R '' (µA)	71 °
8.0SMDJ12A	8.0SMDJ12CA	8PEP	8BEP	12	13.3	14.7	10	19.9	402.1	25.7	2613.7	800	X
8.0SMDJ13A	8.0SMDJ13CA	8PEQ	8BEQ	13	14.4	15.9	10	21.5	372.1	27.8	2418.7	500	Χ
8.0SMDJ14A	8.0SMDJ14CA	8PER	8BER	14	15.6	17.2	10	23.2	344.9	30.0	2241.9	200	X
8.0SMDJ15A	8.0SMDJ15CA	8PES	8BES	15	16.7	18.5	1	24.4	327.9	31.5	2131.4	100	Χ
8.0SMDJ16A	8.0SMDJ16CA	8PET	8BET	16	17.8	19.7	1	26.0	307.7	33.6	2000.1	50	X
8.0SMDJ17A	8.0SMDJ17CA	8PEU	8BEU	17	18.9	20.9	1	27.6	290.0	35.7	1885.0	20	Χ
8.0SMDJ18A	8.0SMDJ18CA	8PEV	8BEV	18	20.0	22.1	1	29.2	274.0	37.7	1781.0	10	X
8.0SMDJ20A	8.0SMDJ20CA	8PEW	8BEW	20	22.2	24.5	1	32.4	247.0	41.9	1605.5	5	Χ
8.0SMDJ22A	8.0SMDJ22CA	8PEX	8BEX	22	24.4	26.9	1	35.5	225.4	45.9	1464.8	5	X
8.0SMDJ24A	8.0SMDJ24CA	8PEZ	8BEZ	24	26.7	29.5	1	38.9	205.7	50.3	1336.8	5	Χ
8.0SMDJ26A	8.0SMDJ26CA	8PFE	8BFE	26	28.9	31.9	1	42.1	190.1	54.4	1235.7	5	X
8.0SMDJ28A	8.0SMDJ28CA	8PFG	8BFG	28	31.1	34.4	1	45.4	176.2	58.7	1145.4	5	Χ
8.0SMDJ30A	8.0SMDJ30CA	8PFK	8BFK	30	33.3	36.8	1	48.4	165.3	62.5	1074.5	5	X
8.0SMDJ33A	8.0SMDJ33CA	8PFM	8BFM	33	36.7	40.6	1	53.3	150.1	68.9	975.7	5	Χ
8.0SMDJ36A	8.0SMDJ36CA	8PFP	8BFP	36	40.0	44.2	1	58.1	137.8	75.1	895.7	5	X
8.0SMDJ40A	8.0SMDJ40CA	8PFR	8BFR	40	44.4	49.1	1	64.5	124.1	83.3	806.7	5	Χ
8.0SMDJ43A	8.0SMDJ43CA	8PFT	8BFT	43	47.8	52.8	1	69.4	115.3	89.7	749.5	5	X
8.0SMDJ45A	8.0SMDJ45CA	8PFV	8BFV	45	50.0	55.3	1	72.7	110.1	93.9	715.7	5	Χ
8.0SMDJ48A	8.0SMDJ48CA	8PFX	8BFX	48	53.3	58.9	1	77.4	103.4	100.0	671.8	5	Χ
8.0SMDJ51A	8.0SMDJ51CA	8PFZ	8BFZ	51	56.7	62.7	1	82.4	97.1	106.5	631.2	5	Χ
8.0SMDJ54A	8.0SMDJ54CA	8PGE	8BGE	54	60.0	66.3	1	87.1	92.0	112.5	598.0	5	Χ
8.0SMDJ58A	8.0SMDJ58CA	8PGG	8BGG	58	64.4	71.2	1	93.6	85.5	120.9	555.8	5	Χ
8.0SMDJ60A	8.0SMDJ60CA	8PGK	8BGK	60	66.7	73.7	1	96.8	82.7	125.1	537.2	5	X
8.0SMDJ64A	8.0SMDJ64CA	8PGM	8BGM	64	71.1	78.6	1	103.0	77.7	133.1	504.9	5	Χ
8.0SMDJ70A	8.0SMDJ70CA	8PGP	8BGB	70	77.8	86.0	1	113.0	71.0	146.0	461.5	5	Χ
8.0SMDJ75A	8.0SMDJ75CA	8PGR	8BGR	75	83.3	92.1	1	121.0	66.2	156.3	430.3	5	Χ
8.0SMDJ78A	8.0SMDJ78CA	8PGT	8BGT	78	86.7	95.8	1	126.0	63.5	162.8	412.8	5	X
8.0SMDJ85A	8.0SMDJ85CA	8PGV	8BGV	85	94.4	104.0	1	137.0	58.4	177.0	379.6	5	X
8.0SMDJ90A	8.0SMDJ90CA	8PGX	8BGX	90	100.0	111.0	1	146.0	55.0	188.6	357.5	5	X
8.0SMDJ100A	8.0SMDJ100CA	8PGZ	8BGZ	100	111.0	123.0	1	162.0	49.4	209.3	321.1	5	X
8.0SMDJ110A	8.0SMDJ110CA	8PHE	8BHE	110	122.0	135.0	1	177.0	45.2	228.7	293.8	5	X

For bidirectional type having $V_{_{\rm R}}$ of 20 volts and less, the I $_{_{\rm R}}$ limit is double.



I-V Curve Characteristics





- P_PPM Peak Pulse Power Dissipation Max power dissipation
- V_B Stand-off Voltage -- Maximum voltage that can be applied to the TVS without operation
- V_{BR} Breakdown Voltage Maximum voltage that flows though the TVS at a specified test current (I₇)
- V_c Clamping Voltage -- Peak voltage measured across the TVS at a specified I_{PPM} (peak impulse current)
- I_{R} Reverse Leakage Current -- Current measured at V_{R}
- V_F Forward Voltage Drop for Uni-directional

Ratings and Characteristic Curves (T_a=25°C unless otherwise noted)

Figure 1 - TVS Transients Clamping Waveform

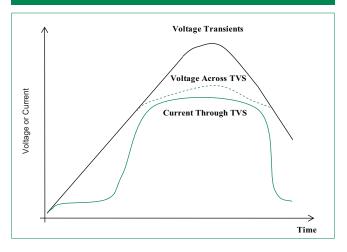
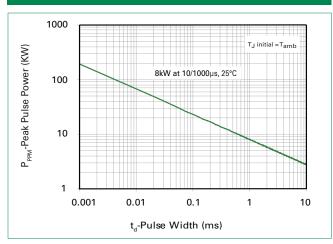


Figure 2 - Peak Pulse Power Rating



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Ratings and Characteristic Curves (T_a=25°C unless otherwise noted) (Continued)

Figure 3 - Peak Pulse Power Derating Curve

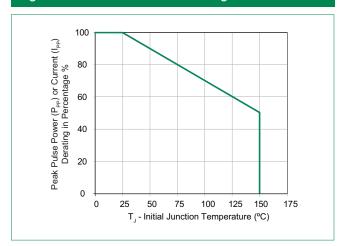


Figure 5 - Typical Junction Capacitance

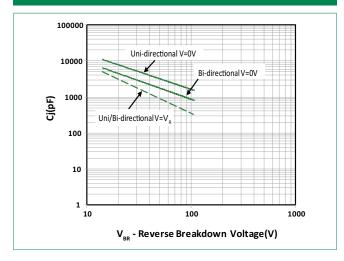


Figure 7 - Maximum Non-Repetitive Peak Forward Surge Current Uni-Directional Only

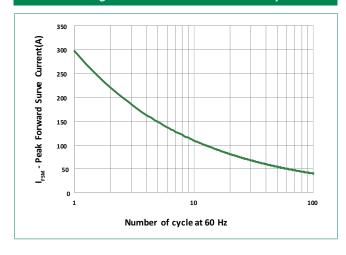


Figure 4 - Pulse Waveform

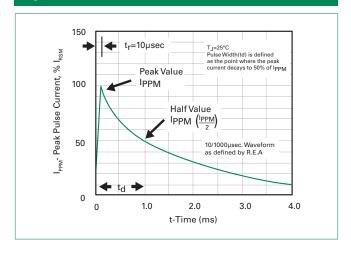


Figure 6 - Typical Transient Thermal Impedance

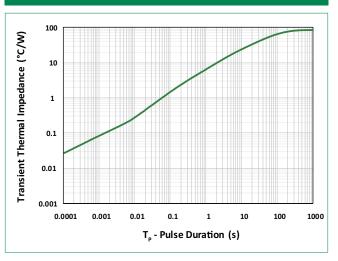
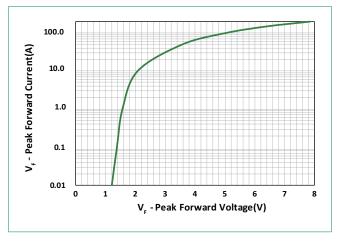


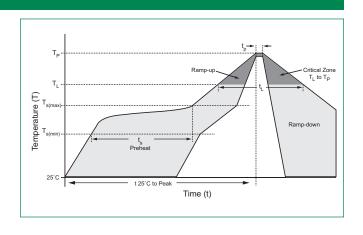
Figure 8 - Peak Forward Voltage Drop vs Peak Forward Current (Typical Values)





Soldering Parameters

D (I C	P.C		
Reflow Cor	ndition	Lead-free assembly	
	-Temperature Min (T _{s(min)})	150°C	
Pre Heat	-Temperature Max (T _{s(max)})	200°C	
	-Time (min to max) (t _s)	60 – 180 secs	
Average ra to peak	mp up rate (Liquidus Temp (T _A)	3°C/second max	
$T_{S(max)}$ to T_A	- Ramp-up Rate	3°C/second max	
Reflow	-Temperature (T _L) (Liquidus)	217°C	
	-Time (min to max) (t _L)	60 – 150 seconds	
Peak Temp	erature (T _P)	260 ^{+0/-5} °C	
Time withi Temperatu	n 5°C of actual peak re (t _p)	20 – 40 seconds	
Ramp-dow	n Rate	6°C/second max	
Time 25°C	to peak Temperature (T _P)	8 minutes Max.	
Do not exc	eed	260°C	



Physical Specifications

Weight	0.011 ounce ,0.3 grams
Case	JEDEC DO214AB. Molded plastic body over glass passivated junction
Polarity	Color band denotes positive end (cathode) except Bidirectional.
Terminal	Matte Tin-plated leads, Solderable per JESD22-B102

Environmental Specifications

High Temp. Storage	JESD22-A103
HTRB	JESD22-A108
Temperature Cycling	JESD22-A104
MSL	JEDEC-J-STD-020, Level 1
H3TRB	JESD22-A101
RSH	JESD22-A111

Dimensions

DO-214AB (SMC J-Bend)

Cathode Band
(for Uni-directional products only)

A

B

H

C

G

J

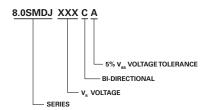
K

L

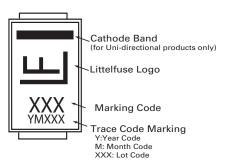
Dimensions	Incl	hes	Millimeters		
Dimensions	Min	Max	Min	Max	
А	0.114	0.126	2.900	3.200	
В	0.260	0.280	6.600	7.110	
С	0.220	0.245	5.590	6.220	
D	0.079	0.103	2.060	2.620	
Е	0.030	0.060	0.760	1.520	
F	-	0.008	-	0.203	
G	0.305	0.320	7.750	8.130	
Н	0.006	0.012	0.152	0.305	
I	0.129	-	3.300	-	
J	0.094	-	2.400	-	
K	-	0.165	-	4.200	
L	0.094	-	2.400	-	



Part Numbering System



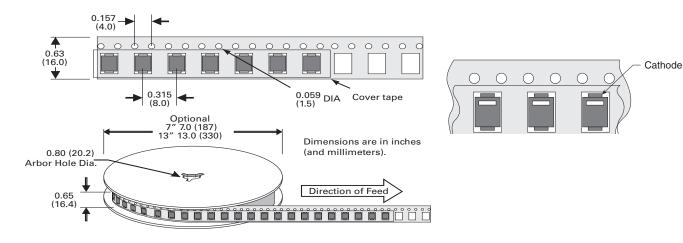
Part Marking System



Packaging Options

Part number	Component Package	Quantity	Packaging Option	Packaging Specification
8.0SMDJxxxXX	DO-214AB	3000	Tape & Reel - 16mm tape/13" reel	EIA STD RS-481
8.0SMDJxxxXX-T7	DO-214AB	500	Tape & Reel – 16mm tape/7" reel	EIA STD RS-481

Tape and Reel Specification



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P6KE8.2A SA110CA SA60CA SA64CA SMBJ12CATR SMBJ8.0A SMLJ30CA-TP ESD112-B1-02EL E6327
ESD119B1W01005E6327XTSA1 ESD5V0J4-TP ESD5V0L1B02VH6327XTSA1 ESD7451N2T5G 19180-510 CPDT-5V0USP-HF
3.0SMCJ33CA-F 3.0SMCJ36A-F HSPC16701B02TP D3V3Q1B2DLP3-7 D55V0M1B2WS-7 DESD5V0U1BL-7B DRTR5V0U4SL-7
SCM1293A-04SO ESD203-B1-02EL E6327 SM12-7 SMF8.0A-TP SMLJ45CA-TP CEN955 W/DATA 82350120560 82356240030
VESD12A1A-HD1-GS08 CPDUR5V0R-HF CPDUR24V-HF CPDQC5V0U-HF CPDQC5V0USP-HF CPDQC5V0-HF D1213A-01LP4-7B
D1213A-02WL-7 ESDLIN1524BJ-HQ 5KP100A 5KP15A 5KP18A